



16K x 1 Static RAM

Features

- Automatic power-down when deselected
- CMOS for optimum speed/power
- High speed
 - 15 ns
- Low active power
 - 275 mW
- Low standby power
 - 83 mW
- TTL-compatible inputs and outputs
- Capable of withstanding greater than 2001V electrostatic discharge
- V_{IH} of 2.2V

Functional Description

The CY7C167A is a high-performance CMOS static RAM organized as 16,384 words by 1 bit. Easy memory expansion is provided by an active LOW chip enable (CE) and three-state drivers. The CY7C167A has an automatic power-down feature, reducing the power consumption by 67% when deselected.

Writing to the device is accomplished when the chip select (CE) and write enable (WE) inputs are both LOW. Data on the input pin (DI) is written into the memory

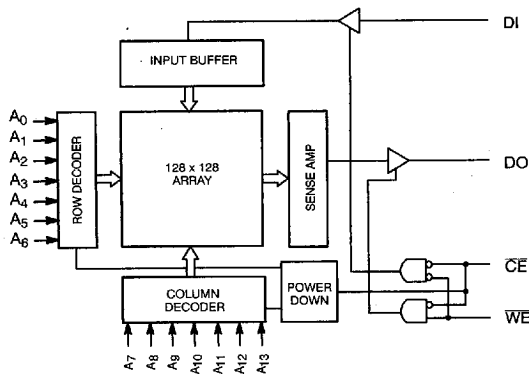
location specified on the address pins (A_0 through A_{13}).

Reading the device is accomplished by taking the chip enable (CE) LOW, while (WE) remains HIGH. Under these conditions, the contents of the location specified on the address pins will appear on the data output (DO) pin.

The output pin remains in a high-impedance state when chip enable is HIGH, or write enable (WE) is LOW.

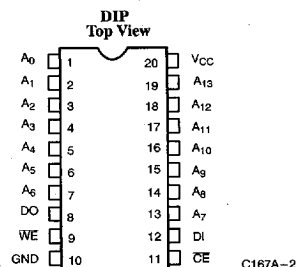
A die coat is used to ensure alpha immunity.

Logic Block Diagram



C167A-1

Pin Configuration



C167A-2

Selection Guide

	7C167A-15	7C167A-20	7C167A-25	7C167A-35	7C167A-45
Maximum Access Time (ns)	15	20	25	35	45
Maximum Operating Current (mA)	Commercial	90	80	60	60
	Military		80	70	60

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-65°C to +150°C
Ambient Temperature with Power Applied	-55°C to +125°C
Supply Voltage to Ground Potential (Pin 20 to Pin 10)	-0.5V to +7.0V
DC Voltage Applied to Outputs in High Z State	-0.5V to +7.0V
DC Input Voltage	-3.0V to +7.0V

Output Current into Outputs (LOW)	20 mA
Static Discharge Voltage (per MIL-STD-883, Method 3015)	>2001V
Latch-Up Current	>200 mA

Operating Range

Range	Ambient Temperature	V _{CC}
Commercial	0°C to +70°C	5V ± 10%
Military ^[1]	-55°C to +125°C	5V ± 10%

Electrical Characteristics Over the Operating Range^[2]

Parameter	Description	Test Conditions	7C167A-15		7C167A-20		7C167A-25		Unit
			Min.	Max.	Min.	Max.	Min.	Max.	
V _{OH}	Output High Voltage	V _{CC} = Min., I _{OH} = -4.0 mA	2.4		2.4		2.4		V
V _{OL}	Output Low Voltage	V _{CC} = Min., I _{OL} = 12.0 mA, 8.0 mA Mil		0.4		0.4		0.4	V
V _{IH}	Input High Voltage		2.2	V _{CC}	2.2	V _{CC}	2.2	V _{CC}	V
V _{IL}	Input Low Voltage ^[3]		-0.5	0.8	-0.5	0.8	-0.5	0.8	V
I _{Ix}	Input Load Current	GND ≤ V _I ≤ V _{CC}	-10	+10	-10	+10	-10	+10	μA
I _{OZ}	Output Leakage Current	GND ≤ V _O ≤ V _{CC} Output Disabled	-10	+10	-10	+10	-10	+10	μA
I _{OS}	Output Short Circuit Current ^[4]	V _{CC} = Max., V _{OUT} = GND		-350		-350		-350	mA
I _{CC}	V _{CC} Operating Supply Current	V _{CC} = Max., I _{OUT} = 0 mA	Com'l	90		80		60	mA
			Mil			80		70	
I _{SB}	Automatic CE Power-Down Current ^[5]	Max. V _{CC} , CE ≥ V _{IH}	Com'l	40		40		20	mA
			Mil			40		20	

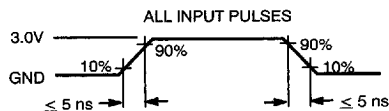
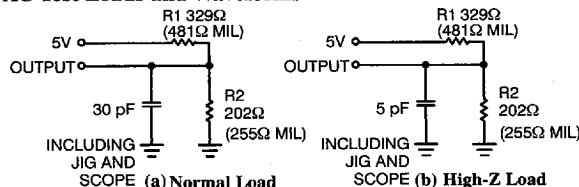
Parameter	Description	Test Conditions	7C167A-35		7C167A-45		Unit
			Min.	Max.	Min.	Max.	
V _{OH}	Output High Voltage	V _{CC} = Min., I _{OH} = -4.0 mA	2.4		2.4		V
V _{OL}	Output Low Voltage	V _{CC} = Min., I _{OL} = 12.0 mA, 8.0 mA Mil		0.4		0.4	V
V _{IH}	Input High Voltage		2.2	V _{CC}	2.2	V _{CC}	V
V _{IL}	Input Low Voltage ^[3]		-0.5	0.8	-0.5	0.8	V
I _{Ix}	Input Load Current	GND ≤ V _I ≤ V _{CC}	-10	+10	-10	+10	μA
I _{OZ}	Output Leakage Current	GND ≤ V _O ≤ V _{CC} Output Disabled	-10	+10	-10	+10	μA
I _{OS}	Output Short Circuit Current ^[4]	V _{CC} = Max., V _{OUT} = GND		-350		-350	mA
I _{CC}	V _{CC} Operating Supply Current	V _{CC} = Max., I _{OUT} = 0 mA	Com'l	60		50	mA
			Mil	60		50	
I _{SB}	Automatic CE Power-Down Current ^[5]	Max. V _{CC} , CE ≥ V _{IH}	Com'l	20			mA
			Mil	20		20	

Notes:

1. T_A is the "instant on" case temperature.
2. See the last page of this specification for Group A subgroup testing information.
3. V_{IL} min. = -3.0V for pulse durations less than 30 ns.
4. Duration of the short circuit should not exceed 30 seconds.
5. A pull-up resistor to V_{CC} on the CE input is required to keep the device deselected during V_{CC} power-up, otherwise I_{SB} will exceed values given.

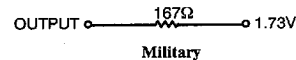
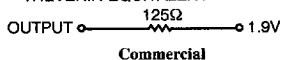
Capacitance^[6]

Parameter	Description	Test Conditions	Max.	Unit
C _{IN}	Input Capacitance	T _A = 25°C, f = 1 MHz, V _{CC} = 5.0V	10	pF
C _{OUT}	Output Capacitance		10	pF
C _{CE}	Chip Enable Capacitance		6	pF

AC Test Loads and Waveforms


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Equivalent to: THÉVENIN EQUIVALENT



C167A-3

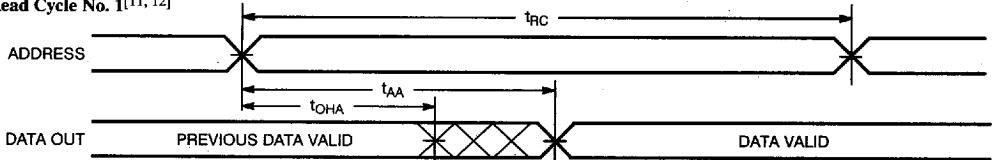
Switching Characteristics Over the Operating Range^[2, 7]

Timing Characteristics for the Operating Mode													
Parameter	Description	7C167A-15		7C167A-20		7C167A-25		7C167A-35		7C167A-45		Unit	
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.		
READ CYCLE													
t _{RC}	Read Cycle Time	Com'l	15		20		25		30				ns
		Mil			20		25		35		40		ns
t _{AA}	Address to Data Valid	Com'l		15		20		25		30			ns
		Mil				20		25		35		40	ns
t _{OH}	Data Hold from Address Change	5		5		5		5		5			ns
t _{ACE}	CE LOW to Data Valid		15		20		25		35		45		ns
t _{LZCE}	CE LOW to Low Z ^[8]	5		5		5		5		5			ns
t _{HZCE}	CE HIGH to High Z ^[8, 9]		8		8		10		15		15		ns
t _{PU}	CE LOW to Power-Up	0		0		0		0		0			ns
t _{PD}	CE HIGH to Power-Down		15		20		20		20		25		ns
WRITE CYCLE ^[10]													
t _{WC}	Write Cycle Time	15		20		20		25		40			ns
t _{SCE}	CE LOW to Write End	12		15		20		25		30			ns
t _{AW}	Address Set-Up to Write End	12		15		20		25		30			ns
t _{HA}	Address Hold from Write End	0		0		0		0		0			ns
t _{SA}	Address Set-Up to Write Start	0		0		0		0		0			ns
t _{PWE}	WE Pulse Width	12		15		15		20		20			ns
t _{SD}	Data Set-Up to Write End	10		10		10		15		15			ns
t _{HD}	Data Hold from Write End	0		0		0		0		0			ns
t _{HZWE}	WE LOW to High Z ^[8, 9]		7		7		7		10		15		ns
t _{LZWE}	WE HIGH to Low Z ^[8]	5		5		5		5		5			ns

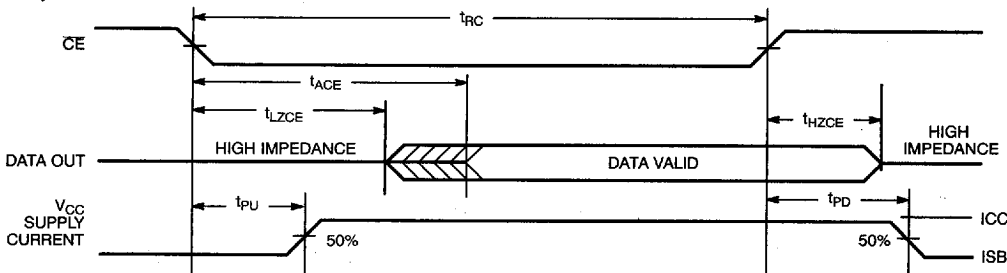
Notes:

- Tested initially and after any design or process changes that may affect these parameters.
- Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading of the specified I_{OL}/I_{OH} and 30-pF load capacitance.
- At any given temperature and voltage condition, t_{HZ} is less than t_{LZ} for any given device.
- t_{HZCE} and t_{HZWE} are tested with C_L = 5 pF as in part (b) of AC Test Loads. Transition is measured ±500 mV from steady state voltage.
- The internal write time of the memory is defined by the overlap of CE LOW and WE LOW. Both signal must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.

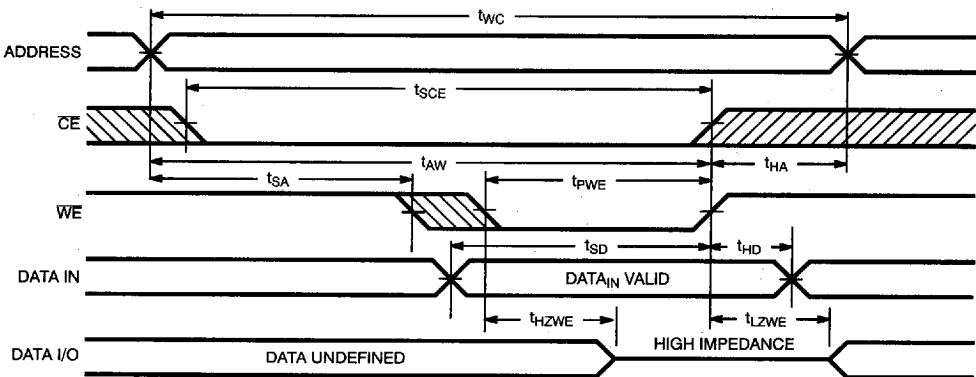
Switching Waveforms

Read Cycle No. 1^[11, 12]


C167A-5

Read Cycle No. 2^[11, 13]


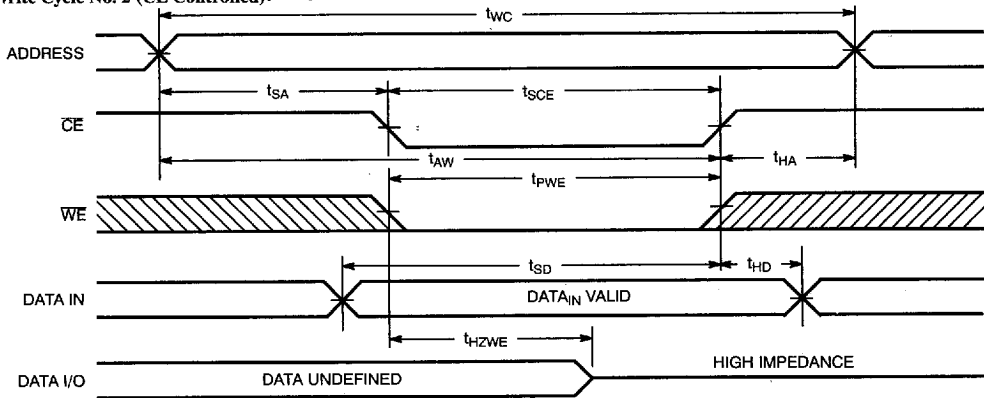
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Write Cycle No. 1 ($\overline{WE}$ Controlled)^[10]


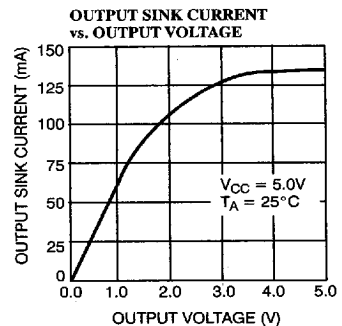
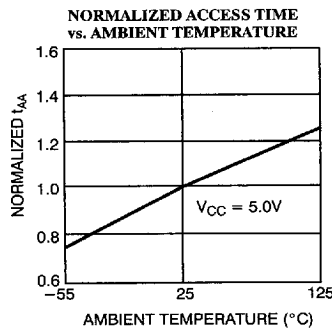
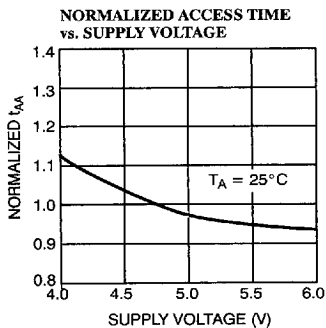
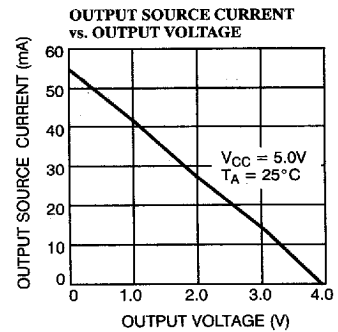
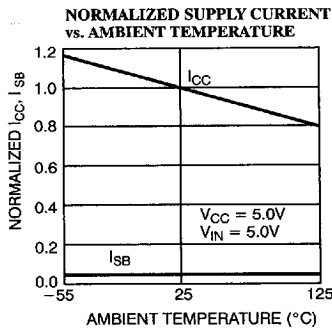
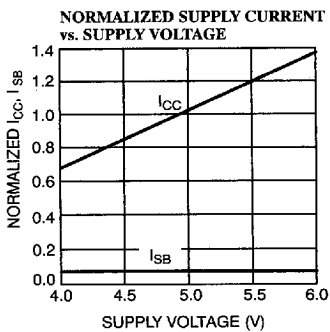
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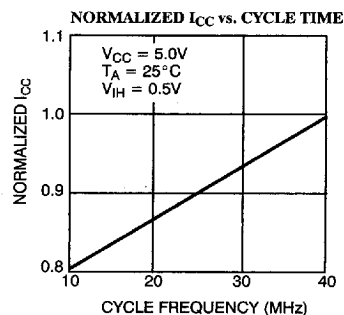
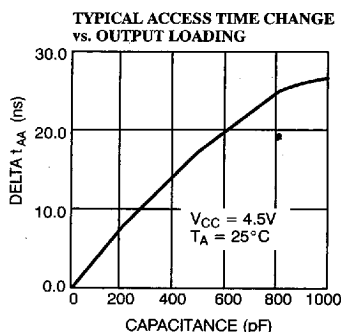
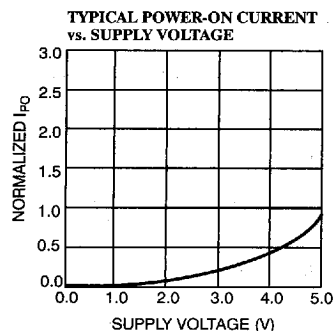
Notes:

11. $\overline{WE}$ is high for read cycle.
12. Device is continuously selected, $\overline{CE} = V_{IL}$.
13. Address valid prior to or coincident with $\overline{CE}$ transition LOW.
14. If $\overline{CE}$ goes HIGH simultaneously with $\overline{WE}$ HIGH, the output remains in a high-impedance state.

Switching Waveforms (continued)
Write Cycle No. 2 (CE Controlled)^[10, 14]


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Typical DC and AC Characteristics


Typical DC and AC Characteristics (continued)

Ordering Information

Speed (ns)	I_{CC} (mA)	Ordering Code	Package Name	Package Type	Operating Range
15	80	CY7C167A-15PC	P5	20-Lead (300-Mil) Molded DIP	Commercial
		CY7C167A-15VC	V5	20-Lead Molded SOJ	
20	80	CY7C167A-20PC	P5	20-Lead (300-Mil) Molded DIP	Commercial
		CY7C167A-20VC	V5	20-Lead Molded SOJ	
		CY7C167A-20DMB	D6	20-Lead (300-Mil) CerDIP	Military
25	60	CY7C167A-25PC	P5	20-Lead (300-Mil) Molded DIP	Commercial
		CY7C167A-25VC	V5	20-Lead Molded SOJ	
		CY7C167A-25DMB	D6	20-Lead (300-Mil) CerDIP	Military
35	60	CY7C167A-35PC	P5	20-Lead (300-Mil) Molded DIP	Commercial
		CY7C167A-35VC	V5	20-Lead Molded SOJ	
		CY7C167A-35DMB	D6	20-Lead (300-Mil) CerDIP	Military
45	50	CY7C167A-45DMB	D6	20-Lead (300-Mil) CerDIP	Military

**MILITARY SPECIFICATIONS**
Group A Subgroup Testing
DC Characteristics

Parameter	Subgroups
V _{OH}	1,2,3
V _{OL}	1,2,3
V _{IH}	1,2,3
V _{IL Max.}	1,2,3
I _{IX}	1,2,3
I _{OZ}	1,2,3
I _{CC}	1,2,3
I _{SB}	1,2,3

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Switching Characteristics

Parameter	Subgroups
READ CYCLE	
t _{RC}	7,8,9,10,11
t _{AA}	7,8,9,10,11
t _{OHA}	7,8,9,10,11
t _{ACE}	7,8,9,10,11
WRITE CYCLE	
t _{WC}	7,8,9,10,11
t _{SCE}	7,8,9,10,11
t _{AW}	7,8,9,10,11
t _{HA}	7,8,9,10,11
t _{SA}	7,8,9,10,11
t _{PWE}	7,8,9,10,11
t _{SD}	7,8,9,10,11
t _{HD}	7,8,9,10,11